

# **AK8772**

Shipped in packet-tape reel(5000pcs/Reel)

AK8772 is ultra-small Hall effect IC of a single silicon chip composed of Hall element and a signal processing IC.

Bipolar Hall Effect Latch Supply Voltage 1.6~5.5 V

Power down Function

Ultra High Sensitivity Bop: 1.8mT

Output CMOS SON

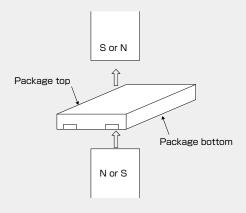
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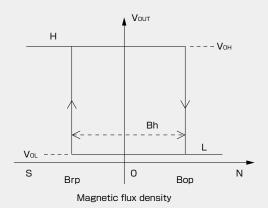
#### Features

- · Precision Bipolar Hall Effect Latch
- $\cdot$  Power manageability through "PDN" pin Current consumption in Power down mode is less than 1  $\mu\rm A$
- $\cdot$  Low current consumption at active mode : less than avg. 150  $\mu A@V_{DD}\!\!=\!\!3V$
- · Ultra small SON package: 1.1×1.4×t0.37mm, Halogen free

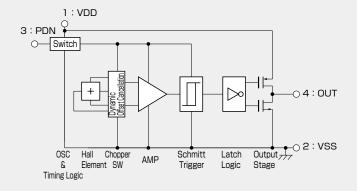


#### Operational Characteristics





## ●Functional Block Diagram



Item	Function		
osc	Generates operating clock		
Timing Logic	Generates timing signal requires for Chopper SW, AMP and other circuits		
Hall Element	Hall element fabricated by CMOS process		
Chopper SW	Performs chopping in order to cancel the offset voltage of Hall sensor		
AMP	Reduce offset voltage and amplifies Hall output voltage		
Schmitt Trigger	Hysteresis comparator		
Latch Logic Output Stage	CMOS output, During the power down mode, output is latched in its previous state		

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## Absolute Maximum Ratings

Item	symbol	Min.	Max.	Unit	Note
Power supply voltage	V <sub>DD</sub>	-0.3	+6.5	V	
Output current	Іоит	-0.5	+0.5	mA	OUT
Input voltage	Vin	-0.3	V <sub>DD</sub> +0.3*	V	PDN
Input current	lin	-10	+10	mA	PDN
Storage temperature	Тѕтс	-55	+125	°C	

<sup>\*)</sup> Less than +6.5V.

Note) Stress beyond these listed values may cause permanent damage to the device.

## Recommended Operating Conditions

Item	symbol	Min.	Typ.	Max.	Unit
Power supply voltage	V <sub>DD</sub>	1.6	3.0	5.5	V
Operating temperature	Ta	-30		+85	°C

### ●Electrical Characteristics (Ta=25°C VDD =3.0V)

Item	symbol	Min.	Тур.	Max.	Unit	Note
Current consumption 1	loo1			1	μΑ	PDN=0V
Current consumption 2	IDD2		60	150	μΑ	PDN=VDD,Average
PDN input current	lın	-1		1	μΑ	
PDN input H voltage	ViH	0.7V <sub>DD</sub>			٧	
PDN input L voltage	VIL			0.3	V	
High level output voltage	Vон	V <sub>DD</sub> -0.4			V	I <sub>ОUТ</sub> =0.5mA
Low level output voltage	Vol			0.4	٧	Iouт=+0.5mA
PDN mode transition time 1	T <sub>PD</sub> 1			(36.6)	μs	*Active→PDN
PDN mode transition time 2	T <sub>PD</sub> 2			100	μs	PDN→Active
Pulse drive period	T <sub>PD</sub> 3	0.5	1.0	1.5	ms	When PDN=VDD
Pulse drive time	T <sub>PD</sub> 4	12.2	24.4	36.6	μs	
PDN 'H' input pulse width	Tw	100			μs	

<sup>\*)</sup> This transition time is not guaranteed by inspection because PDN input timing and internal timing are asynchronous

## ●Magnetic Characteristics① (Ta=25°C VDD=3.0V)

Item	symbol	Min.	Тур.	Max.	Unit
Operating point	Вор		1.8	4.0	mT
Releasing point	Brp	-4.0	-1.8		mT
Hysteresis	Bh		3.6		mT

## ● Magnetic Characteristics② (Ta= $-30\sim+85$ °C V<sub>DD</sub>= $1.6\sim5.5$ V)

Item	symbol	Min.	Тур.	Max.	Unit
Operating point	Вор		1.8	4.2	mT
Releasing point	Brp	-4.2	-1.8		mT
Hysteresis	Bh		3.6		mT

Note) The specifications in Magnetic Characteristics ② are design targets.

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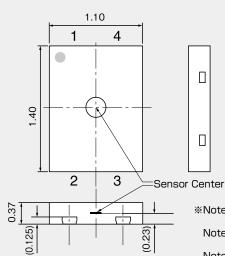
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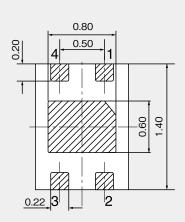
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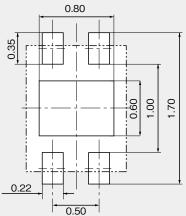
## Package (Unit:mm)





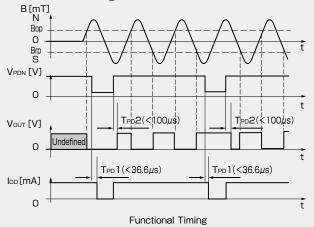
- \*Note 1) Sensitive area position referenced to
  - the center of package within  $\phi$ 0.3mm circle.
  - Note 2) Tolerances of dimension otherwise noted is  $\pm 0.05$ mm.
  - Note 3) Hatched area is plated.
- Note 4) Center pad area (TAB) should be tied to the VSS or floating

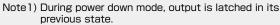
## ●Footprint (for reference)



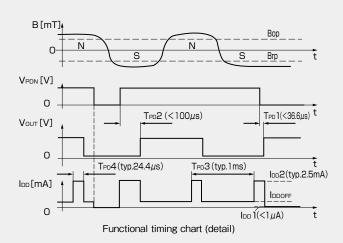
No.	Pin name	Function	Note
1	VDD	Power supply	
2	VSS	Ground	
3	PDN	Power down	CMOS Input. This pin has to be
		H:Device active	tied to "H" level when external
		L:Device power down	power control is not used.
4	OUT	Output	CMOS Output

## Function Timing Chart





Note2) When VDD is supplied, the time from reaching  $V_{DD}$ = 1.6V to the update of the output state is equal to  $T_{PD2}$ .

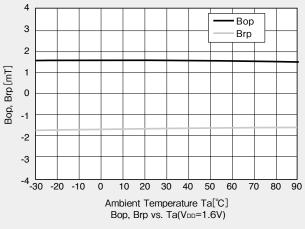


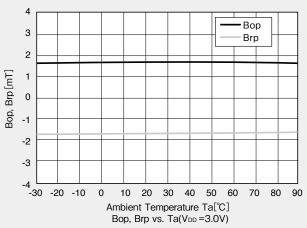
When PDN pin set to 'L' from 'H' during sampling is performing, the device transits to power down mode after sampling is completed. And when PDN pin set to 'L' from 'H' while sampling is not performing, the device transits to power down mode immediately.

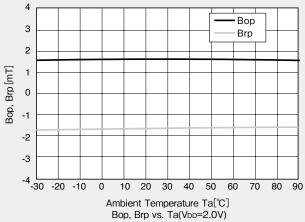
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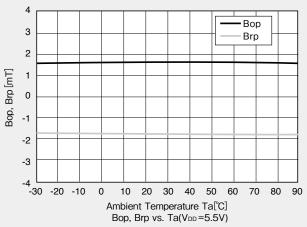
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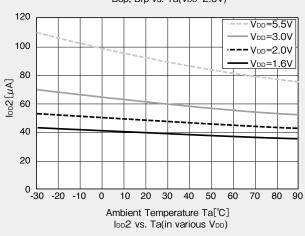
## ●Typical Characteristic Data (for reference)

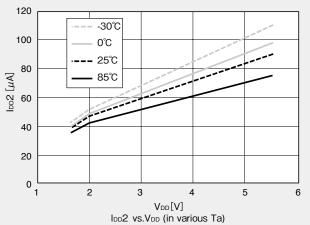




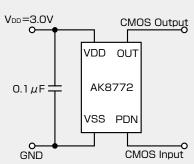








## Application Circuit



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